

# N-Channel 200 V (D-S) MOSFET

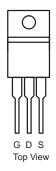
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
200	0.409 at V <sub>GS</sub> = 10 V	22		

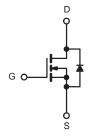
### **FEATURES**

- DT-Trench Power MOSFET
- 175 °C Junction Temperature
- PWM Optimized
- 100 % R<sub>g</sub> Tested Compliant to RoHS Directive 2002/95/EC



### TO-220AB





N-Channel MOSFET

### **APPLICATIONS**

Primary Side Switch

<b>ABSOLUTE MAXIMUM RATINGS</b> $(T_A =$	25 °C, unless othe	rwise noted)			
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	200	V	
Gate-Source Voltage		V <sub>GS</sub>	± 20	7 v	
Continuous Drain Current (T <sub>.I</sub> = 175 °C) <sup>b</sup>	T <sub>C</sub> = 25 °C	I <sub>D</sub>	22		
Continuous Diam Current (1) = 175 C)	T <sub>C</sub> = 125 °C	'D	13	I	
Pulsed Drain Current		I <sub>DM</sub>	67	А	
Continuous Source Current (Diode Conduction)		I <sub>S</sub>	19		
Avalanche Current		I <sub>AS</sub>	19		
Single Pulse Avalanche Energy	L = 0.1 mH	E <sub>AS</sub>	18	mJ	
Maximum Dayar Dissination	T <sub>C</sub> = 25 °C	P <sub>D</sub>	136 <sup>b</sup>	W	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	] '	3 <sup>a</sup>	]	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
lungting to Ameliant	t ≤ 10 s	- R <sub>thJA</sub>	15	18	°C/W
Junction-to-Ambient <sup>a</sup>	Steady State		40	50	
Junction-to-Case (Drain)		R <sub>thJC</sub>	0.85	1.1	

- a. Surface mounted on 1" x 1" FR4 board.
- b. See SOA curve for voltage derating.

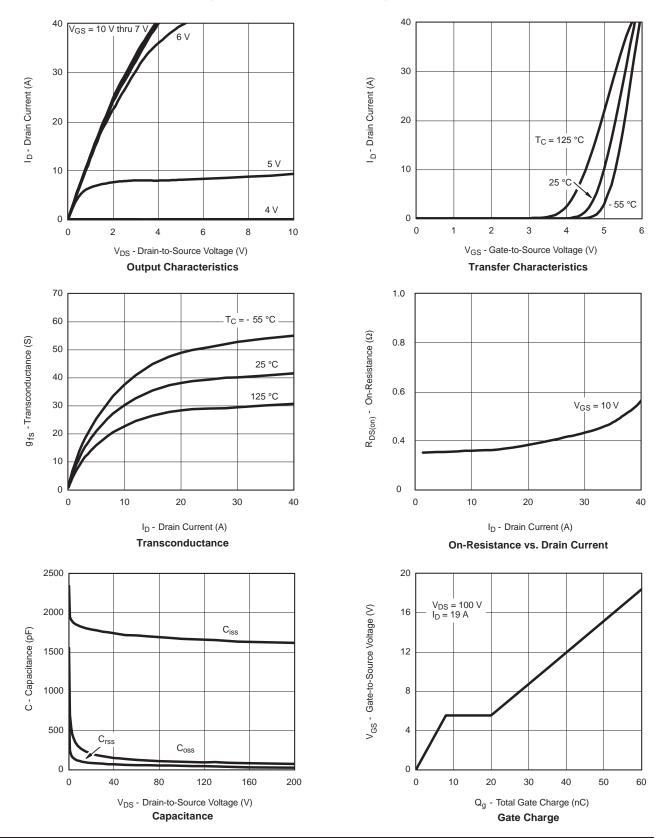
Parameter	Symbol	Test Conditions	Min.	Typ. <sup>a</sup>	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	200				
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2		4	· V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
		V <sub>DS</sub> = 200 V, V <sub>GS</sub> = 0 V			1	μА	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 200 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125 °C			50		
		V <sub>DS</sub> = 200 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 175 °C			250		
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 10 V	40			Α	
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 5 A		0.409	0.465		
	D	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 5 A, T <sub>J</sub> = 125 °C			0.497		
Drain-Source On-State Resistance <sup>b</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 5 A, T <sub>J</sub> = 175 °C			0.515	Ω	
		V <sub>GS</sub> = 6 V, I <sub>D</sub> = 5 A		0.416	0.452		
Forward Transconductance <sup>b</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 19 A		35		S	
Dynamic <sup>a</sup>							
Input Capacitance	C <sub>iss</sub>			1800		pF	
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 25 V, F = 1 MHz		180			
Reverse Transfer Capacitance	C <sub>rss</sub>			80			
Total Gate Charge <sup>c</sup>	Qg			34	51		
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 19 \text{ A}$		8		nC	
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$			12			
Gate Resistance	R <sub>g</sub>		0.5		2.9	Ω	
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			15	25		
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 100 \text{ V}, R_L = 5.2 \Omega$ $I_D \cong 19 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		50	75	ns	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>			30	45		
Fall Time <sup>c</sup>	t <sub>f</sub>			60	90		
Source-Drain Diode Ratings and Chara	acteristics (7	<sub>C</sub> = 25 °C)					
Pulsed Current	I <sub>SM</sub>				67	А	
Diode Forward Voltage <sup>b</sup>	V <sub>SD</sub>	I <sub>F</sub> = 19 A, V <sub>GS</sub> = 0 V		0.9	1.5	V	

- a. Guaranteed by design, not subject to production testing. b. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

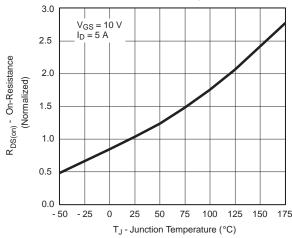
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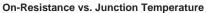
# TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



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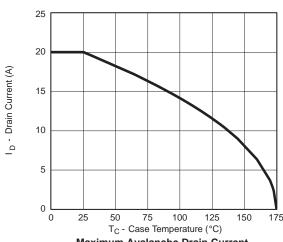




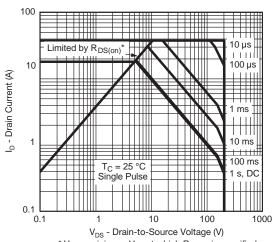
# T<sub>J</sub> = 150 °C T<sub>J</sub> = 150 °C T<sub>J</sub> = 25 °C 10 V<sub>SD</sub> - Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage

### THERMAL RATINGS

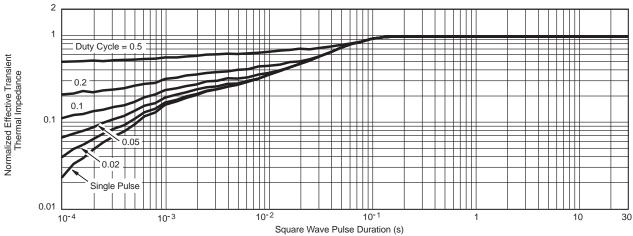


Maximum Avalanche Drain Current vs. Case Temperature



\*  $V_{GS}$  > minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Case



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